

## LMV3xxA Dual Low-Voltage Rail-to-Rail Output Operational Amplifier

### 1 Features

- Rail-to-Rail Output
- Low Input Offset Voltage:  $\pm 1$  mV
- Unity-Gain Bandwidth: 1 MHz
- Low Broadband Noise:  $30 \text{ nV}/\sqrt{\text{Hz}}$
- Low Input Bias Current: 10 pA
- Low Quiescent Current: 80  $\mu\text{A}/\text{Ch}$
- Unity-Gain Stable
- Internal RFI and EMI Filter
- Operational at Supply Voltages as Low as 2.5 V
- Easier to Stabilize With Higher Capacitive Load Due to Resistive Open-Loop Output Impedance
- Extended Temperature Range:  $-40^\circ\text{C}$  to  $+125^\circ\text{C}$

### 2 Applications

- HVAC: Heating, Ventilating, and Air Conditioning
- Large and Small Appliances
- Power Modules
- Motor Control: AC Induction
- Smoke Detectors
- Motion Detectors
- Wearable Devices
- EPOS
- Barcode Scanners
- Personal Electronics
- Active Filters
- Sensor Signal Conditioning
- Low-Side Current Sensing

### 3 Description

The LMV3xxA family includes dual - (LMV358A) low-voltage (2.5 V to 5.5 V) operational amplifiers (op amps) with rail-to-rail output swing capabilities. These op amps provide a cost-effective solution for space-constrained applications, such as large appliances, smoke detectors, and personal electronics, where low-voltage operation and high capacitive-load drive are required. The capacitive-load drive of the LMV3xxA family is 500 pF, and the resistive open-loop output impedance makes it easy to stabilize with much higher capacitive loads. These op amps are designed specifically for low-voltage operation (2.5 V to 5.5 V) with performance specifications similar to the LMV3xx devices.

The robust design of the LMV3xxA family simplifies circuit design. The op amps feature unity-gain stability, an integrated RFI and EMI rejection filter, and no-phase reversal in overdrive condition.

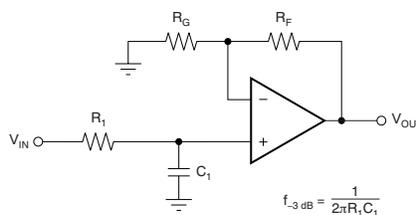
The LMV3xxA family is available in industry-standard packages, such as SOIC, MSOP, SOT-23 and TSSOP packages.

#### Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)
LMV358A	SOIC (8)	3.91 mm x 4.90 mm
	WSON (8)	2.00 mm x 2.00 mm
	VSSOP (8)	3.00 mm x 3.00 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

#### Single-Pole, Low-Pass Filter



$$\frac{V_{OUT}}{V_{IN}} = \left(1 + \frac{R_F}{R_G}\right) \left(\frac{1}{1 + sR_1C_1}\right)$$



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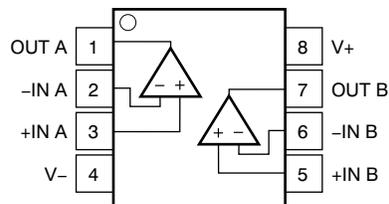
## 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

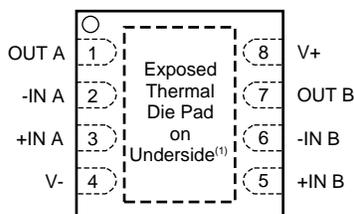
DATE	REVISION	NOTES
December 2017	*	Initial release.

## 5 Pin Configuration and Functions

**LMV358A D, DGK Packages  
8-Pin SOIC, VSSOP  
Top View**



**LMV358A DSG Package  
8-Pin WSON With Exposed Thermal Pad  
Top View**



(1) Connect thermal pad to V–

### Pin Functions: LMV358A

PIN		I/O	DESCRIPTION
NAME	NO.		
–IN A	2	I	Inverting input, channel A
+IN A	3	I	Noninverting input, channel A
–IN B	6	I	Inverting input, channel B
+IN B	5	I	Noninverting input, channel B
OUT A	1	O	Output, channel A
OUT B	7	O	Output, channel B
V–	4	—	Negative (lowest) supply or ground (for single-supply operation)
V+	8	—	Positive (highest) supply

## 6 Specifications

### 6.1 Absolute Maximum Ratings

 over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

		MIN	MAX	UNIT
Supply voltage ([V+] – [V–])		0	6	V
Signal input pins	Voltage <sup>(2)</sup>	Common-mode		V
		(V–) – 0.5	(V+) + 0.5	
	Differential	(V+) – (V–) + 0.2		V
Current <sup>(2)</sup>		–10	10	mA
Output short-circuit <sup>(3)</sup>		Continuous		mA
Operating, T <sub>A</sub>		–55	150	°C
Junction, T <sub>J</sub>			150	°C
Storage, T <sub>stg</sub>		–65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) Input pins are diode-clamped to the power-supply rails. Input signals that may swing more than 0.5 V beyond the supply rails must be current limited to 10 mA or less.
- (3) Short-circuit to ground, one amplifier per package.

### 6.2 ESD Ratings

		VALUE	UNIT
V <sub>(ESD)</sub>	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±2000
		Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	±1000

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V <sub>S</sub>	Supply voltage	2.5	5.5	V
T <sub>A</sub>	Specified temperature	–40	125	°C

### 6.4 Thermal Information: LMV358A

THERMAL METRIC <sup>(1)</sup>		LMV358A	UNIT
		D (SOIC)	
		8 PINS	
R <sub>θJA</sub>	Junction-to-ambient thermal resistance	147.4	°C/W
R <sub>θJC(top)</sub>	Junction-to-case (top) thermal resistance	94.3	°C/W
R <sub>θJB</sub>	Junction-to-board thermal resistance	89.5	°C/W
ψ <sub>JT</sub>	Junction-to-top characterization parameter	47.3	°C/W
ψ <sub>JB</sub>	Junction-to-board characterization parameter	89	°C/W

- (1) For more information about traditional and new thermal metrics, see [Semiconductor and IC Package Thermal Metrics application report](#).

## 6.5 Electrical Characteristics

For  $V_S = (V+) - (V-) = 2.5\text{ V to }5.5\text{ V}$  ( $\pm 0.9\text{ V to } \pm 2.75\text{ V}$ ),  $T_A = 25\text{ }^\circ\text{C}$ ,  $R_L = 10\text{ k}\Omega$  connected to  $V_S / 2$ , and  $V_{CM} = V_{OUT} = V_S / 2$  (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>OFFSET VOLTAGE</b>						
$V_{OS}$	Input offset voltage	$V_S = 5\text{ V}$		$\pm 1$	$\pm 4$	mV
		$V_S = 5\text{ V}$ , $T_A = -40^\circ\text{C to }125^\circ\text{C}$			$\pm 5$	mV
$dV_{OS}/dT$	$V_{OS}$ vs temperature	$T_A = -40^\circ\text{C to }125^\circ\text{C}$		$\pm 1$		$\mu\text{V}/^\circ\text{C}$
PSRR	Power-supply rejection ratio	$V_S = 2.5\text{ to }5.5\text{ V}$ , $V_{CM} = (V-)$	78	100		dB
<b>INPUT VOLTAGE RANGE</b>						
$V_{CM}$	Common-mode voltage range	No phase reversal, rail-to-rail input	$(V-) - 0.1$		$(V+) - 1$	V
CMRR	Common-mode rejection ratio	$V_S = 2.5\text{ V}$ , $(V-) - 0.1\text{ V} < V_{CM} < (V+) - 1.4\text{ V}$ $T_A = -40^\circ\text{C to }125^\circ\text{C}$		86		dB
		$V_S = 5.5\text{ V}$ , $(V-) - 0.1\text{ V} < V_{CM} < (V+) - 1.4\text{ V}$ $T_A = -40^\circ\text{C to }125^\circ\text{C}$		95		dB
		$V_S = 5.5\text{ V}$ , $(V-) - 0.1\text{ V} < V_{CM} < (V+) + 0.1\text{ V}$ $T_A = -40^\circ\text{C to }125^\circ\text{C}$	63	77		dB
		$V_S = 2.5\text{ V}$ , $(V-) - 0.1\text{ V} < V_{CM} < (V+) + 0.1\text{ V}$ $T_A = -40^\circ\text{C to }125^\circ\text{C}$		68		dB
<b>INPUT BIAS CURRENT</b>						
$I_B$	Input bias current	$V_S = 5\text{ V}$		$\pm 10$		pA
$I_{OS}$	Input offset current			$\pm 3$		pA
<b>NOISE</b>						
$E_n$	Input voltage noise (peak-to-peak)	$f = 0.1\text{ Hz to }10\text{ Hz}$ , $V_S = 5\text{ V}$		5.1		$\mu\text{V}_{PP}$
$e_n$	Input voltage noise density	$f = 1\text{ kHz}$ , $V_S = 5\text{ V}$		33		$\text{nV}/\sqrt{\text{Hz}}$
		$f = 10\text{ kHz}$ , $V_S = 5\text{ V}$		30		$\text{nV}/\sqrt{\text{Hz}}$
$i_n$	Input current noise density	$f = 1\text{ kHz}$ , $V_S = 5\text{ V}$		25		$\text{fA}/\sqrt{\text{Hz}}$
<b>INPUT CAPACITANCE</b>						
$C_{ID}$	Differential			1.5		pF
$C_{IC}$	Common-mode			5		pF
<b>OPEN-LOOP GAIN</b>						
$A_{OL}$	Open-loop voltage gain	$V_S = 5.5\text{ V}$ , $(V-) + 0.05\text{ V} < V_O < (V+) - 0.05\text{ V}$ , $R_L = 10\text{ k}\Omega$	100	115		dB
		$V_S = 2.5\text{ V}$ , $(V-) + 0.04\text{ V} < V_O < (V+) - 0.04\text{ V}$ , $R_L = 10\text{ k}\Omega$		98		dB
		$V_S = 2.5\text{ V}$ , $(V-) + 0.1\text{ V} < V_O < (V+) - 0.1\text{ V}$ , $R_L = 2\text{ k}\Omega$		112		dB
		$V_S = 5.5\text{ V}$ , $(V-) + 0.15\text{ V} < V_O < (V+) - 0.15\text{ V}$ , $R_L = 2\text{ k}\Omega$		128		dB
<b>FREQUENCY RESPONSE</b>						
GBW	Gain-bandwidth product	$V_S = 5\text{ V}$		1		MHz
$\phi_m$	Phase margin	$V_S = 5.5\text{ V}$ , $G = 1$		76		degrees
SR	Slew rate	$V_S = 5\text{ V}$		1.7		V/ $\mu\text{s}$
$t_s$	Settling time	To 0.1%, $V_S = 5\text{ V}$ , 2-V Step, $G = +1$ , $C_L = 100\text{ pF}$		3		$\mu\text{s}$
		To 0.01%, $V_S = 5\text{ V}$ , 2-V Step, $G = +1$ , $C_L = 100\text{ pF}$		4		$\mu\text{s}$
$t_{OR}$	Overload recovery time	$V_S = 5\text{ V}$ , $V_{IN} \times \text{gain} > V_S$		0.9		$\mu\text{s}$
THD+N	Total harmonic distortion + noise	$V_S = 5.5\text{ V}$ , $V_{CM} = 2.5\text{ V}$ , $V_O = 1\text{ V}_{RMS}$ , $G = +1$ , $f = 1\text{ kHz}$ , 80 kHz measurement BW		0.005		%
<b>OUTPUT</b>						
$V_O$	Voltage output swing from supply rails	$V_S = 5.5\text{ V}$ , $R_L = 10\text{ k}\Omega$		20	50	mV
		$V_S = 5.5\text{ V}$ , $R_L = 2\text{ k}\Omega$		40	75	mV
$I_{SC}$	Short-circuit current	$V_S = 5.5\text{ V}$		$\pm 40$		mA
$Z_O$	Open-loop output impedance	$V_S = 5\text{ V}$ , $f = 1\text{ MHz}$		1200		$\Omega$
<b>POWER SUPPLY</b>						
$V_S$	Specified voltage range		2.5 ( $\pm 1.25$ )		5.5 ( $\pm 2.75$ )	V
$I_Q$	Quiescent current per amplifier	$I_O = 0\text{ mA}$ , $V_S = 5.5\text{ V}$		80	125	$\mu\text{A}$
		$I_O = 0\text{ mA}$ , $V_S = 5.5\text{ V}$ , $T_A = -40^\circ\text{C to }125^\circ\text{C}$			150	$\mu\text{A}$

**Electrical Characteristics (continued)**

For  $V_S = (V+) - (V-) = 2.5\text{ V to }5.5\text{ V}$  ( $\pm 0.9\text{ V to } \pm 2.75\text{ V}$ ),  $T_A = 25\text{ }^\circ\text{C}$ ,  $R_L = 10\text{ k}\Omega$  connected to  $V_S / 2$ , and  $V_{CM} = V_{OUT} = V_S / 2$  (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Power-on time	$V_S = 0\text{ V to }5\text{ V}$ , to 90% $I_Q$ level		50		$\mu\text{s}$

## 6.6 Typical Characteristics

at  $T_A = 25^\circ\text{C}$ ,  $V_+ = 2.75\text{ V}$ ,  $V_- = -2.75\text{ V}$ ,  $R_L = 10\text{ k}\Omega$  connected to  $V_S / 2$ ,  $V_{CM} = V_S / 2$ , and  $V_{OUT} = V_S / 2$  (unless otherwise noted)

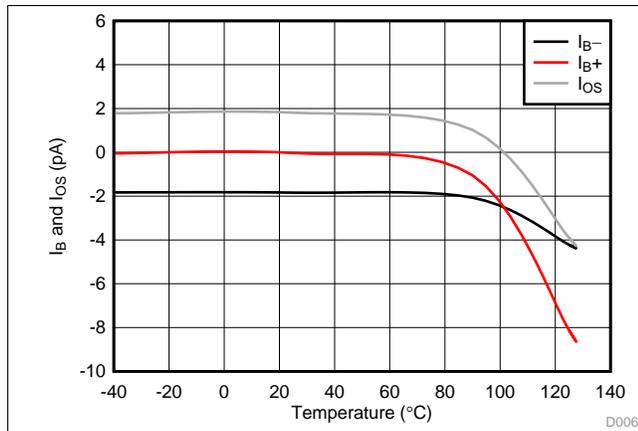


Figure 1.  $I_B$  and  $I_{OS}$  vs Temperature

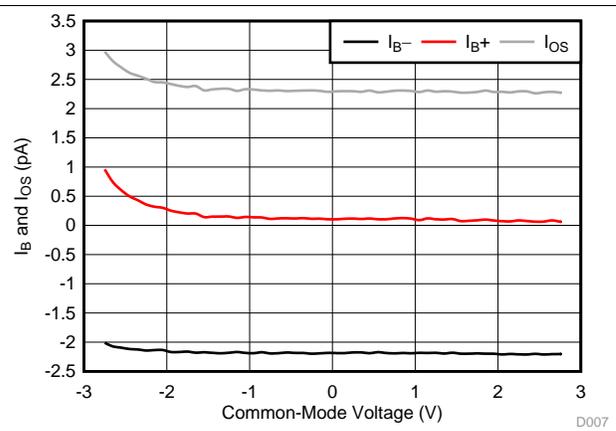


Figure 2.  $I_B$  and  $I_{OS}$  vs Common-Mode Voltage

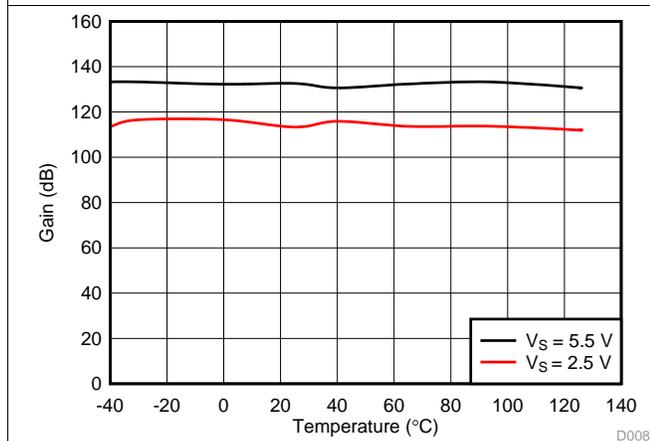


Figure 3. Open-Loop Gain vs Temperature

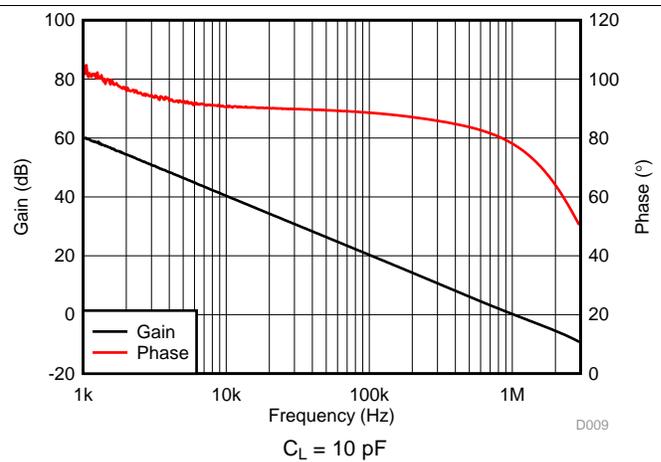


Figure 4. Open-Loop Gain and Phase vs Frequency

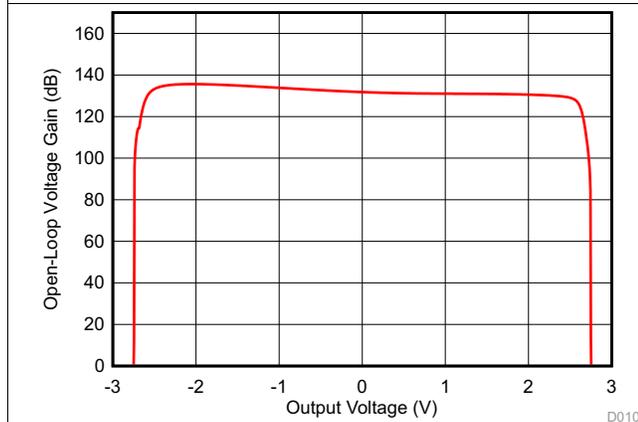


Figure 5. Open-Loop Gain vs Output Voltage

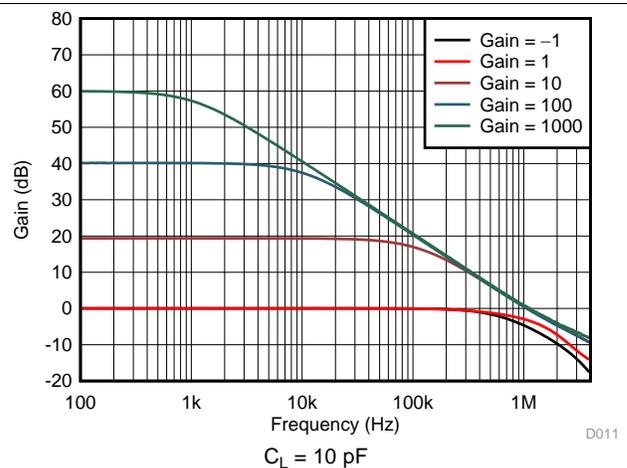


Figure 6. Closed-Loop Gain vs Frequency

Typical Characteristics (continued)

at  $T_A = 25^\circ\text{C}$ ,  $V_+ = 2.75\text{ V}$ ,  $V_- = -2.75\text{ V}$ ,  $R_L = 10\text{ k}\Omega$  connected to  $V_S / 2$ ,  $V_{CM} = V_S / 2$ , and  $V_{OUT} = V_S / 2$  (unless otherwise noted)

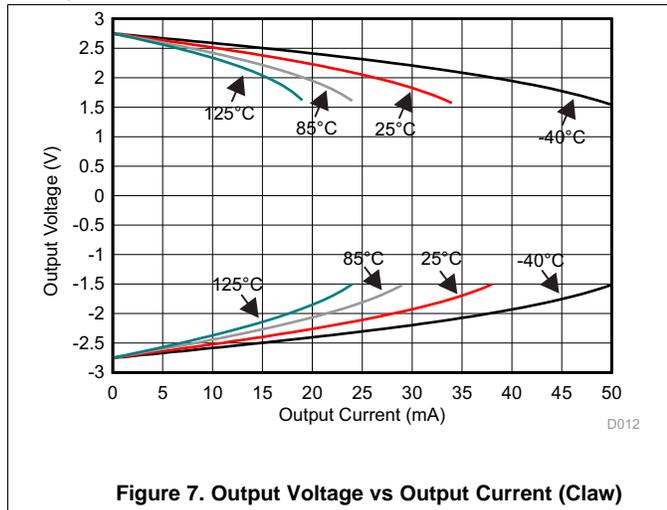


Figure 7. Output Voltage vs Output Current (Claw)

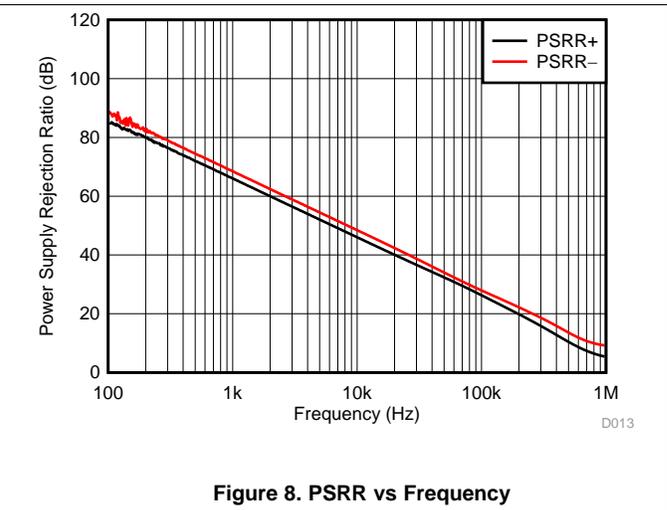


Figure 8. PSRR vs Frequency

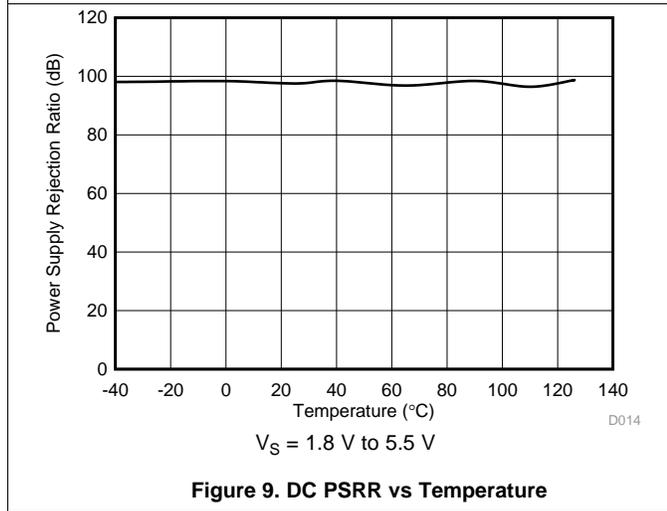


Figure 9. DC PSRR vs Temperature

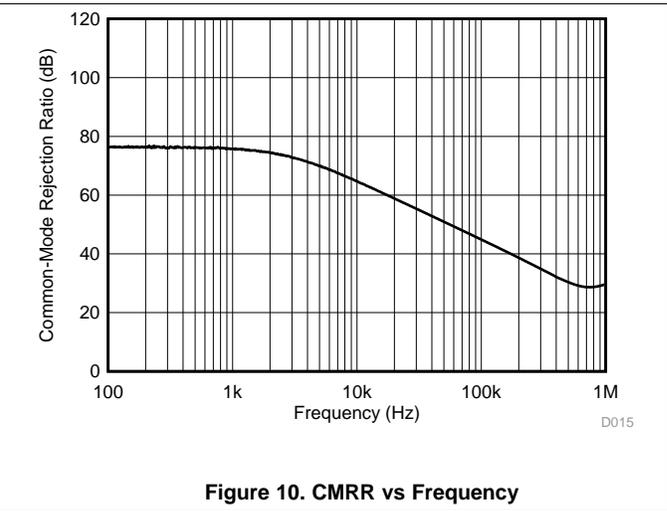
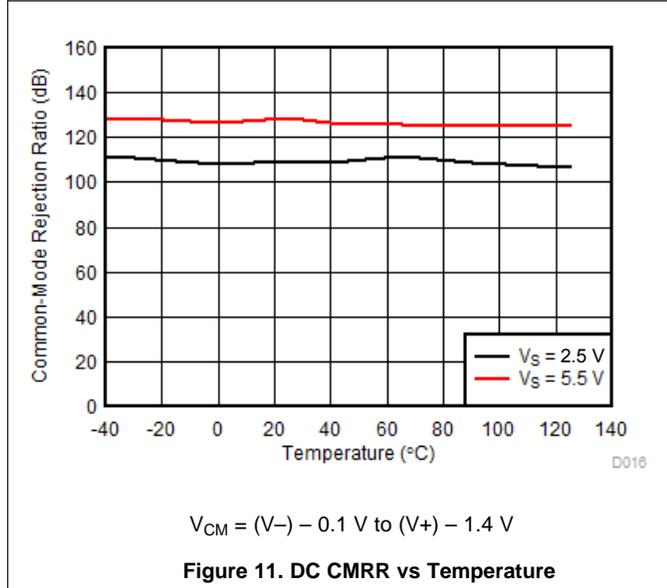


Figure 10. CMRR vs Frequency



$$V_{CM} = (V_-) - 0.1\text{ V to } (V_+) - 1.4\text{ V}$$

Figure 11. DC CMRR vs Temperature

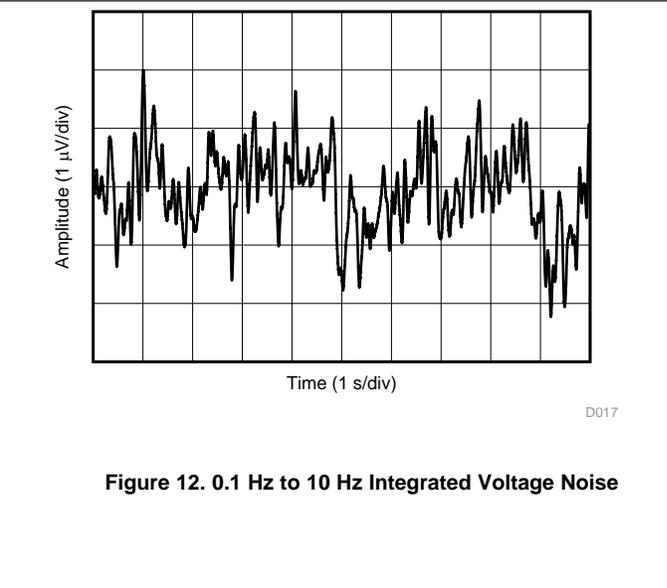
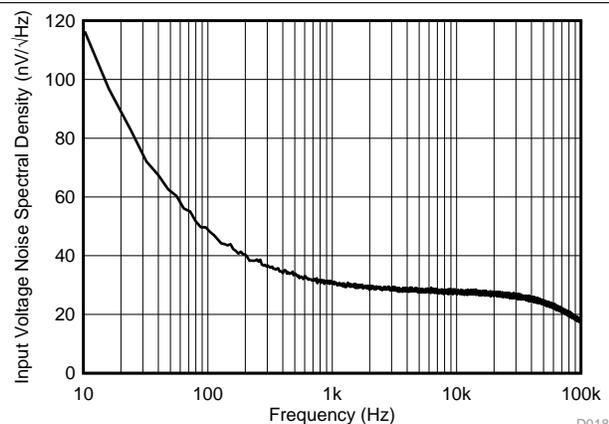


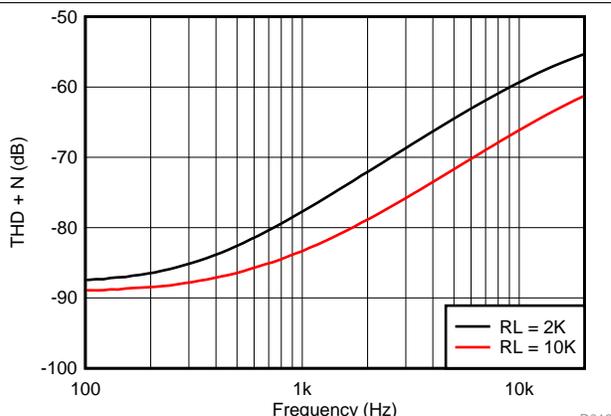
Figure 12. 0.1 Hz to 10 Hz Integrated Voltage Noise

**Typical Characteristics (continued)**

at  $T_A = 25^\circ\text{C}$ ,  $V_+ = 2.75\text{ V}$ ,  $V_- = -2.75\text{ V}$ ,  $R_L = 10\text{ k}\Omega$  connected to  $V_S / 2$ ,  $V_{CM} = V_S / 2$ , and  $V_{OUT} = V_S / 2$  (unless otherwise noted)

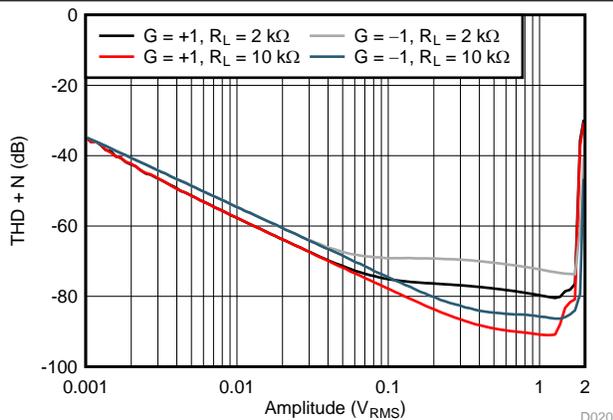


**Figure 13. Input Voltage Noise Spectral Density**



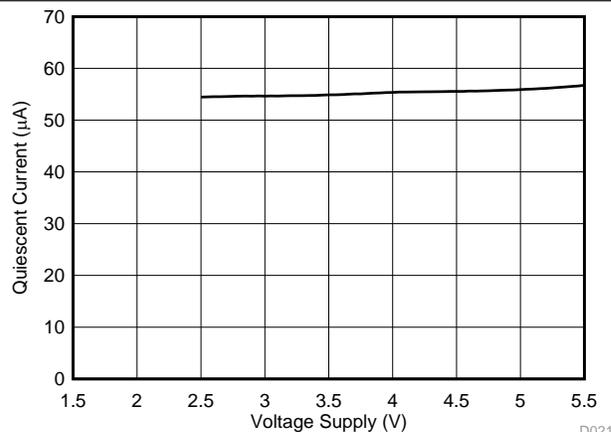
$V_S = 5.5\text{ V}$ ,  $V_{CM} = 2.5\text{ V}$ ,  $G = 1$ ,  $BW = 80\text{ kHz}$ ,  $V_{OUT} = 0.5 V_{RMS}$

**Figure 14. THD + N vs Frequency**

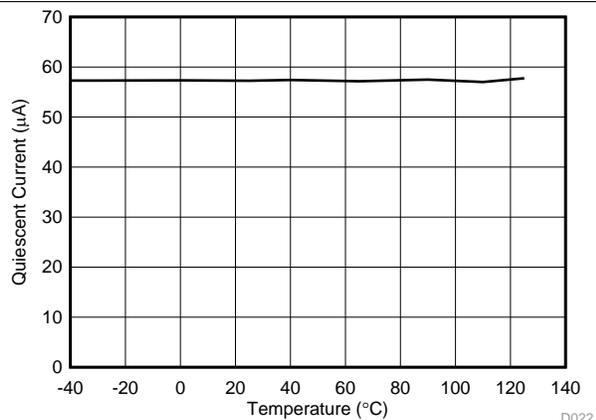


$V_S = 5.5\text{ V}$ ,  $V_{CM} = 2.5\text{ V}$ ,  $f = 1\text{ kHz}$ ,  $G = 1$ ,  $BW = 80\text{ kHz}$

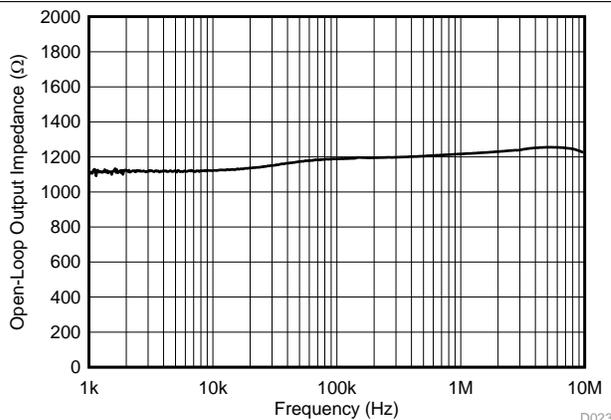
**Figure 15. THD + N vs Amplitude**



**Figure 16. Quiescent Current vs Supply Voltage**



**Figure 17. Quiescent Current vs Temperature**



**Figure 18. Open-Loop Output Impedance vs Frequency**

Typical Characteristics (continued)

at  $T_A = 25^\circ\text{C}$ ,  $V_+ = 2.75\text{ V}$ ,  $V_- = -2.75\text{ V}$ ,  $R_L = 10\text{ k}\Omega$  connected to  $V_S / 2$ ,  $V_{CM} = V_S / 2$ , and  $V_{OUT} = V_S / 2$  (unless otherwise noted)

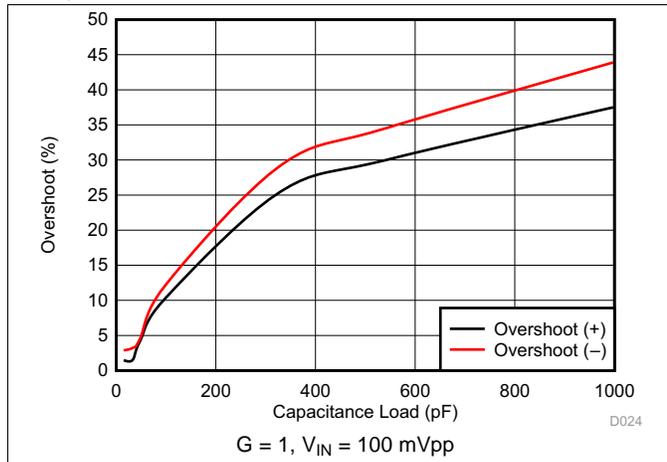


Figure 19. Small Signal Overshoot vs Capacitive Load

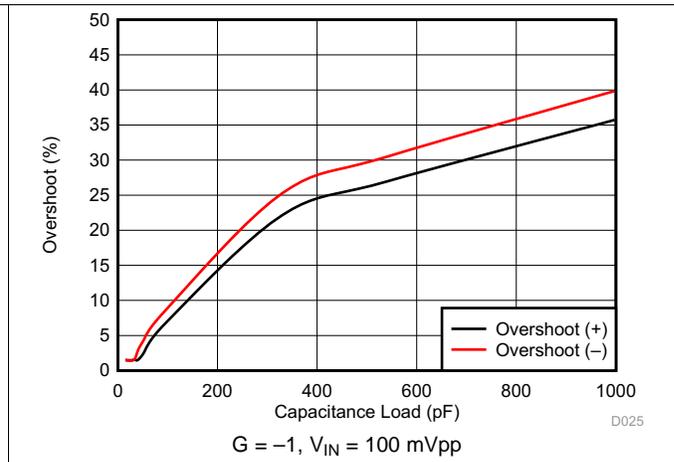


Figure 20. Small Signal Overshoot vs Capacitive Load

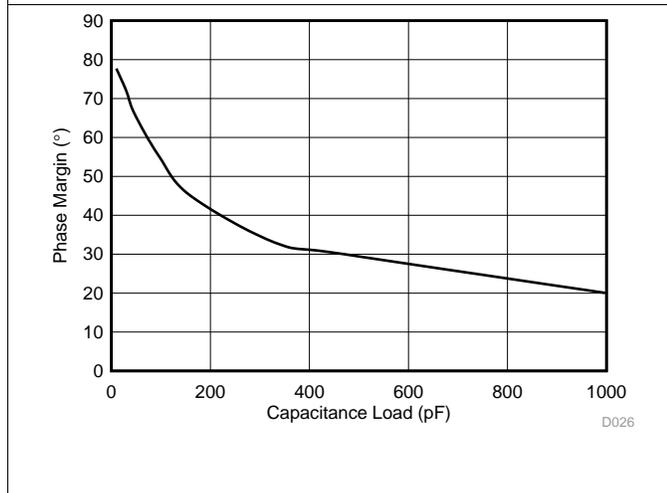


Figure 21. Phase Margin vs Capacitive Load

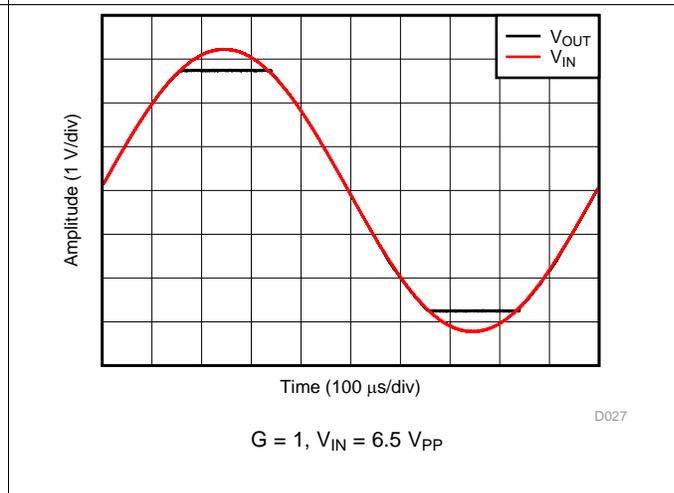


Figure 22. No Phase Reversal

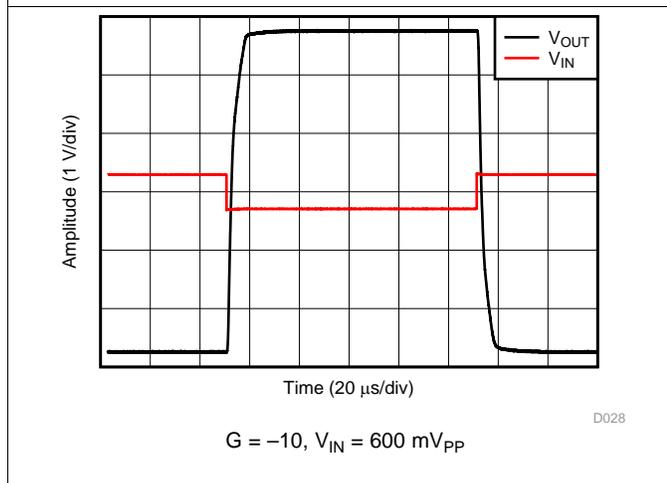


Figure 23. Overload Recovery

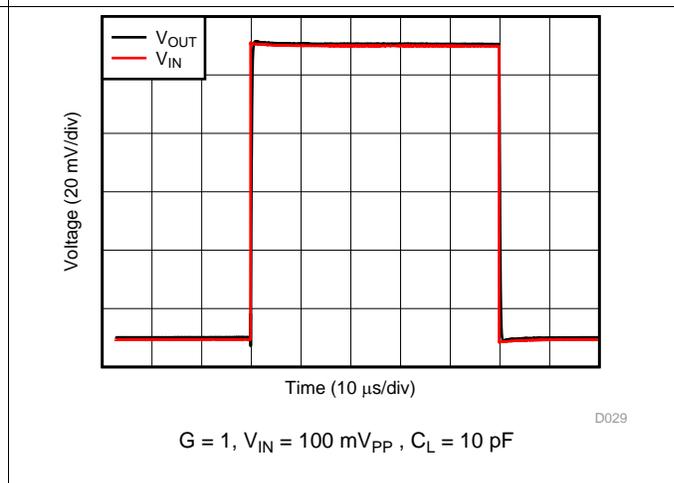
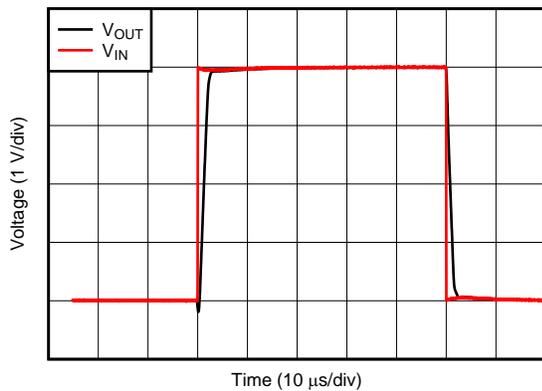


Figure 24. Small-Signal Step Response

Typical Characteristics (continued)

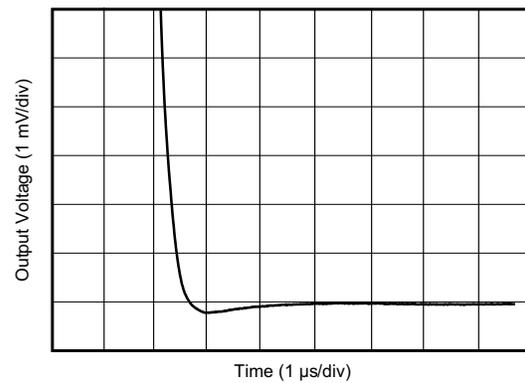
at  $T_A = 25^\circ\text{C}$ ,  $V_+ = 2.75\text{ V}$ ,  $V_- = -2.75\text{ V}$ ,  $R_L = 10\text{ k}\Omega$  connected to  $V_S / 2$ ,  $V_{CM} = V_S / 2$ , and  $V_{OUT} = V_S / 2$  (unless otherwise noted)



$G = 1$ ,  $V_{IN} = 4\text{ V}_{PP}$ ,  $C_L = 10\text{ pF}$

D030

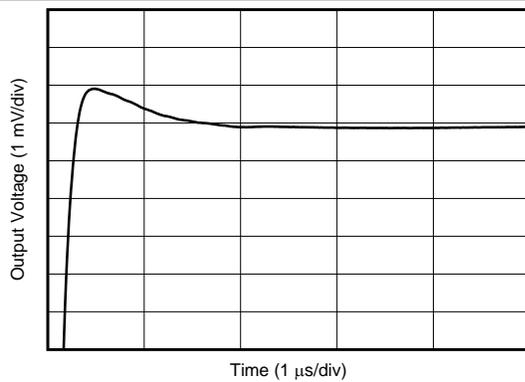
Figure 25. Large-Signal Step Response



$G = 1$ ,  $C_L = 100\text{ pF}$ , 2-V step

D031

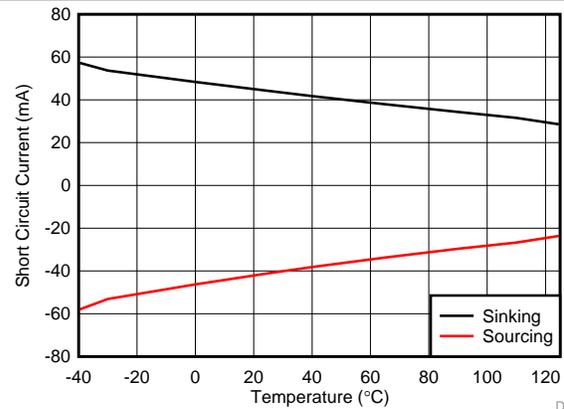
Figure 26. Large-Signal Settling Time (Negative)



$G = 1$ ,  $C_L = 100\text{ pF}$ , 2-V step

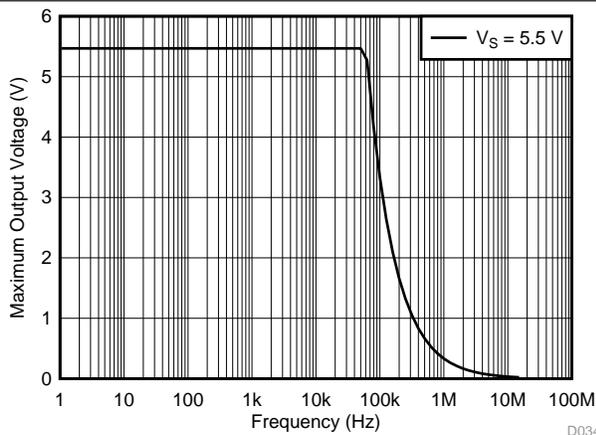
D032

Figure 27. Large-Signal Settling Time (Positive)



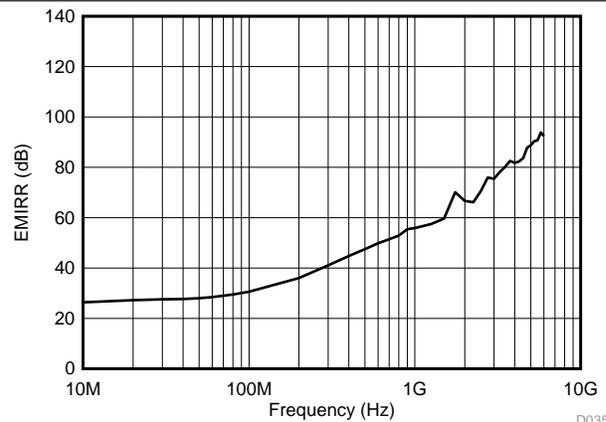
D033

Figure 28. Short-Circuit Current vs Temperature



D034

Figure 29. Maximum Output Voltage vs Frequency



D035

Figure 30. Electromagnetic Interference Rejection Ratio Referred to Noninverting Input (EMIRR+) vs Frequency

### Typical Characteristics (continued)

at  $T_A = 25^\circ\text{C}$ ,  $V_+ = 2.75\text{ V}$ ,  $V_- = -2.75\text{ V}$ ,  $R_L = 10\text{ k}\Omega$  connected to  $V_S / 2$ ,  $V_{CM} = V_S / 2$ , and  $V_{OUT} = V_S / 2$  (unless otherwise noted)

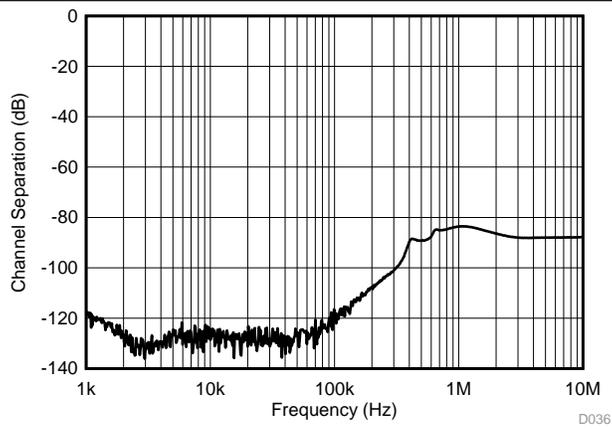


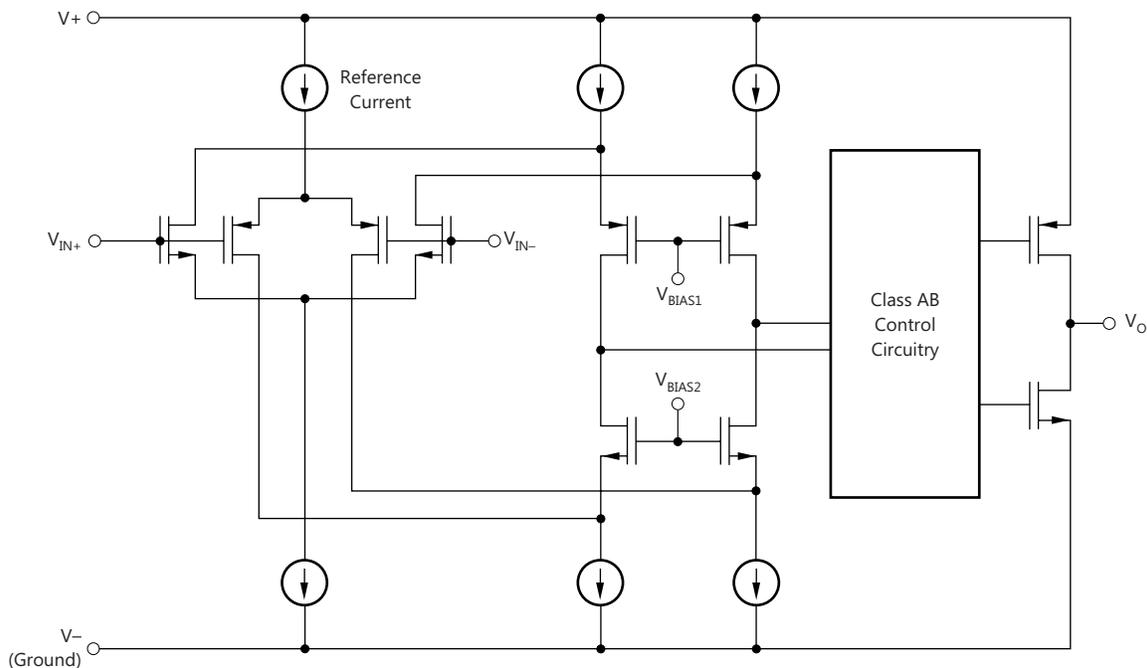
Figure 31. Channel Separation

## 7 Detailed Description

### 7.1 Overview

The LMV3xxA series is a family of low-power, rail-to-rail output op amps. These devices operate from 2.5 V to 5.5 V, are unity-gain stable, and are designed for a wide range of general-purpose applications. The input common-mode voltage range includes the negative rail and allows the LMV3xxA series to be used in many single-supply applications. Rail-to-rail output swing significantly increases dynamic range, especially in low-supply applications, and makes them suitable for driving sampling analog-to-digital converters (ADCs).

### 7.2 Functional Block Diagram



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## 7.3 Feature Description

### 7.3.1 Operating Voltage

The LMV3xxA series of op amps are ensured for operation from 2.5 V to 5.5 V. In addition, many specifications apply from  $-40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ . Parameters that vary significantly with operating voltages or temperature are shown in the section.

### 7.3.2 Rail-to-Rail Input

The input common-mode voltage range of the LMV3xxA family extends 100 mV beyond the negative supply rail and within 1 V below the positive rail for the full supply voltage range of 2.5 V to 5.5 V. This performance is achieved with a P-channel differential pair, as shown in the [Functional Block Diagram](#). Additionally, a complementary N-channel differential pair has been included in parallel to eliminate issues with phase reversal that are common with previous generations of op amps. However, the N-channel pair is not optimized for operation. TI recommends limiting any voltages applied at the inputs to less than  $V_{CC} - 1\text{V}$  to ensure that the op amp conforms to the specifications detailed in the [Electrical Characteristics](#) table.

### 7.3.3 Rail-to-Rail Output

Designed as a low-power, low-voltage operational amplifier, the LMV3xxA series delivers a robust output drive capability. A class-AB output stage with common-source transistors achieves full rail-to-rail output swing capability. For resistive loads of 10 k $\Omega$ , the output swings to within 20 mV of either supply rail, regardless of the applied power-supply voltage. Different load conditions change the ability of the amplifier to swing close to the rails.

### 7.3.4 Overload Recovery

Overload recovery is defined as the time required for the operational amplifier output to recover from a saturated state to a linear state. The output devices of the operational amplifier enter a saturation region when the output voltage exceeds the rated operating voltage, because of the high input voltage or the high gain. After the device enters the saturation region, the charge carriers in the output devices require time to return to the linear state. After the charge carriers return to the linear state, the device begins to slew at the specified slew rate. Therefore, the propagation delay (in case of an overload condition) is the sum of the overload recovery time and the slew time. The overload recovery time for the LMV3xxA series is approximately 850 ns.

## 7.4 Device Functional Modes

The LMV3xxA family has a single functional mode. The devices are powered on as long as the power-supply voltage is between and 5.5 V ( $\pm 2.75\text{ V}$ ).

## 8 Application and Implementation

### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

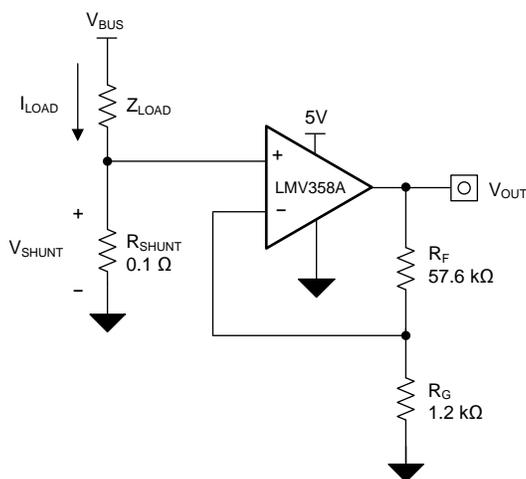
### 8.1 Application Information

The LMV3xxA is a family of low-power, rail-to-rail output operational amplifiers specifically designed for portable applications. The devices operate from 2.5 V to 5.5 V, are unity-gain stable, and are suitable for a wide range of general-purpose applications. The class AB output stage is capable of driving less than or equal to 10-k $\Omega$  loads connected to any point between V+ and V-. The input common-mode voltage range includes the negative rail, and allows the LMV3xxA to be used in many single-supply applications.

### 8.2 Typical Application

#### 8.2.1 LMV3xxA Low-Side, Current Sensing Application

Figure 32 shows the LMV3xxA configured in a low-side current sensing application.



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**Figure 32. LMV3xxA in a Low-Side, Current-Sensing Application**

## Typical Application (continued)

### 8.2.1.1 Design Requirements

The design requirements for this design are:

- Load current: 0 A to 1 A
- Output voltage: 4.9 V
- Maximum shunt voltage: 100 mV

### 8.2.1.2 Detailed Design Procedure

The transfer function of the circuit in is given in [Equation 1](#):

$$V_{OUT} = I_{LOAD} \times R_{SHUNT} \times \text{Gain} \quad (1)$$

The load current ( $I_{LOAD}$ ) produces a voltage drop across the shunt resistor ( $R_{SHUNT}$ ). The load current is set from 0 A to 1 A. To keep the shunt voltage below 100 mV at maximum load current, the largest shunt resistor is shown using [Equation 2](#):

$$R_{SHUNT} = \frac{V_{SHUNT\_MAX}}{I_{LOAD\_MAX}} = \frac{100\text{mV}}{1\text{A}} = 100\text{m}\Omega \quad (2)$$

Using [Equation 2](#),  $R_{SHUNT}$  is calculated to be 100 m $\Omega$ . The voltage drop produced by  $I_{LOAD}$  and  $R_{SHUNT}$  is amplified by the LMV3xxA to produce an output voltage of approximately 0 V to 4.9 V. The gain needed by the LMV3xxA to produce the necessary output voltage is calculated using [Equation 3](#):

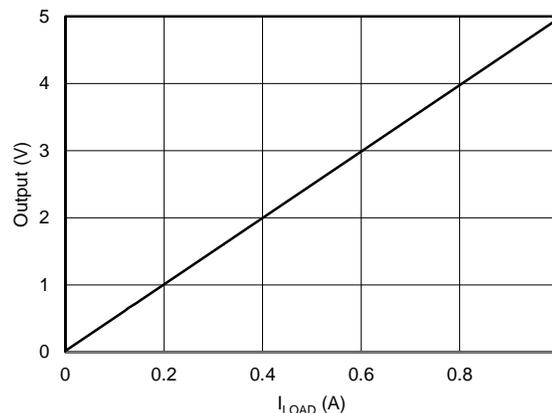
$$\text{Gain} = \frac{(V_{OUT\_MAX} - V_{OUT\_MIN})}{(V_{IN\_MAX} - V_{IN\_MIN})} \quad (3)$$

Using [Equation 3](#), the required gain is calculated to be 49 V/V, which is set with resistors  $R_F$  and  $R_G$ . [Equation 4](#) sizes the resistors  $R_F$  and  $R_G$ , to set the gain of the LMV3xxA to 49 V/V.

$$\text{Gain} = 1 + \frac{(R_F)}{(R_G)} \quad (4)$$

Selecting  $R_F$  as 57.6 k $\Omega$  and  $R_G$  as 1.2 k $\Omega$  provides a combination that equals 49 V/V. [Figure 33](#) shows the measured transfer function of the circuit shown in [Figure 32](#).

### 8.2.1.3 Application Curve

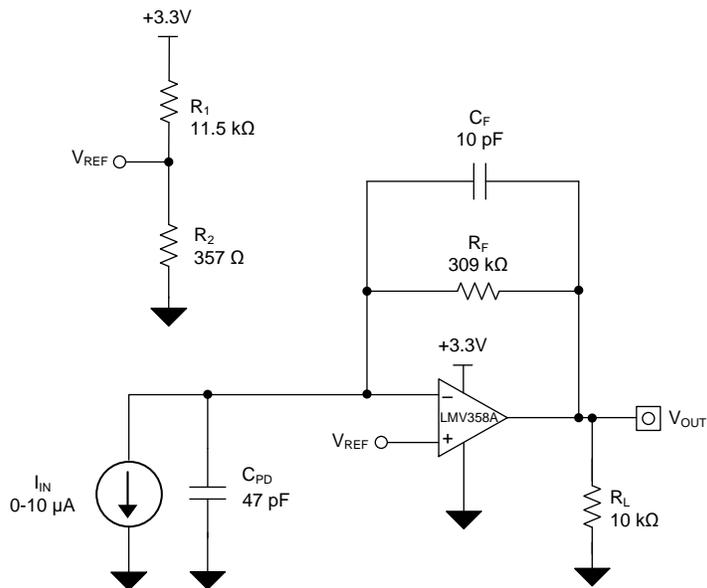


**Figure 33. Low-Side, Current-Sense Transfer Function**

**Typical Application (continued)**

**8.2.2 Single-Supply Photodiode Amplifier**

Photodiodes are used in many applications to convert light signals to electrical signals. The current through the photodiode is proportional to the light energy applied to the current, and is commonly in the range of a few hundred picoamps to a few tens of microamps. An amplifier in a transimpedance configuration is typically used to convert the low-level photodiode current to a voltage signal for processing in an MCU. The circuit shown in Figure 34 is an example single-supply photodiode amplifier circuit using the LMV358A.



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**Figure 34. Single-Supply Photodiode Amplifier Circuit**

## Typical Application (continued)

### 8.2.2.1 Design Requirements

The design requirements for this design are:

- Supply Voltage: 3.3 V
- Input: 0  $\mu$ A to 10  $\mu$ A
- Output: 0.1 V to 3.2 V
- Bandwidth: 50 kHz

### 8.2.2.2 Detailed Design Procedure

The transfer function between the output voltage,  $V_{OUT}$ , the input current,  $I_{IN}$ , and the reference voltage,  $V_{REF}$ , is defined in [Equation 5](#).

$$V_{OUT} = I_{IN} \times R_F + V_{REF} \quad (5)$$

Where

$$V_{REF} = V_+ \times \left( \frac{R_1 \times R_2}{R_1 + R_2} \right) \quad (6)$$

Set  $V_{REF}$  to 100mV to meet the minimum output voltage level by setting  $R_1$  and  $R_2$  to meet the required ratio calculated in [Equation 7](#).

$$\frac{V_{REF}}{V_+} = \frac{0.1 \text{ V}}{3.3 \text{ V}} = 0.0303 \quad (7)$$

The closest resistor ratio to meet this ratio sets  $R_1$  to 11.5 k $\Omega$  and  $R_2$  to 357  $\Omega$ .

The required feedback resistance can be calculated based on the input current and desired output voltage.

$$R_F = \frac{V_{OUT} - V_{REF}}{I_{IN}} = \frac{3.2 \text{ V} - 0.1 \text{ V}}{10 \mu\text{A}} = 310 \frac{\text{kV}}{\text{A}} \approx 309 \text{ k}\Omega \quad (8)$$

Calculate the value for the feedback capacitor based  $R_F$  and the desired –3-dB bandwidth, ( $f_{-3dB}$ ) using [Equation 9](#).

$$C_F = \frac{1}{2 \times \pi \times R_F \times f_{-3dB}} = \frac{1}{2 \times \pi \times 309 \text{ k}\Omega \times 50 \text{ kHz}} = 10.3 \text{ pF} \approx 10 \text{ pF} \quad (9)$$

The minimum op amp bandwidth required for this application is based on the value of  $R_F$ ,  $C_F$  and the capacitance on the  $IN-$  pin of the LMV358A which is equal to the sum of the photodiode shunt capacitance,  $C_{PD}$ , the common-mode input capacitance  $C_{CM}$  and the differential input capacitance  $C_D$  as shown in [Equation 10](#).

$$C_{IN} = C_{PD} + C_{CM} + C_D = 47 \text{ pF} + 5 \text{ pF} + 1 \text{ pF} = 53 \text{ pF} \quad (10)$$

The minimum op amp bandwidth is calculated in [Equation 11](#).

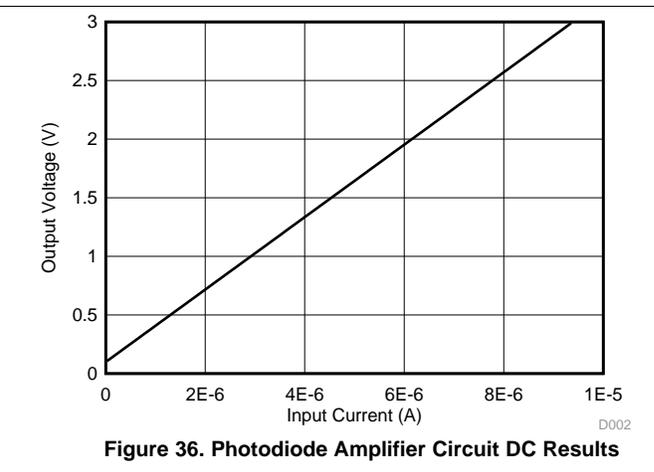
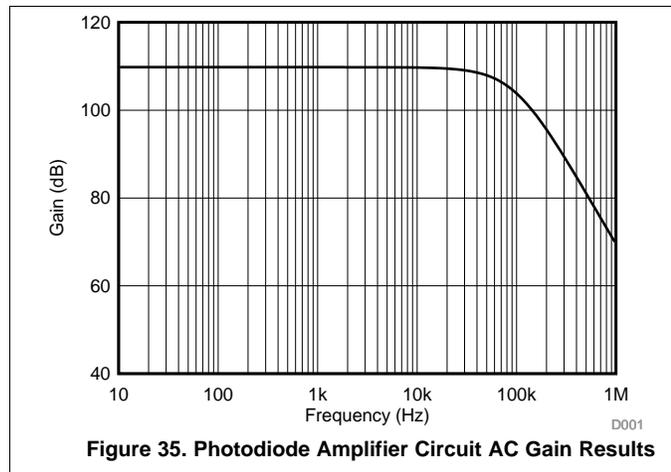
$$f_{-BGW} \geq \frac{C_{IN} + C_F}{2 \times \pi \times R_F \times C_F^2} \geq 324 \text{ kHz} \quad (11)$$

The 1-MHz bandwidth of the LMV3xxA meets the minimum bandwidth requirement and remains stable in this application configuration.

## Typical Application (continued)

### 8.2.2.3 Application Curves

The measured current-to-voltage transfer function for photodiode amplifier circuit is shown in [Figure 35](#). The measured DC performance of the photodiode amplifier circuit is shown in [Figure 36](#).



## 9 Power Supply Recommendations

The LMV3xxA series is specified for operation from 2.5 V to 5.5 V ( $\pm 1.25$  V to  $\pm 2.75$  V); many specifications apply from  $-40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ . The section presents parameters that may exhibit significant variance with regard to operating voltage or temperature.

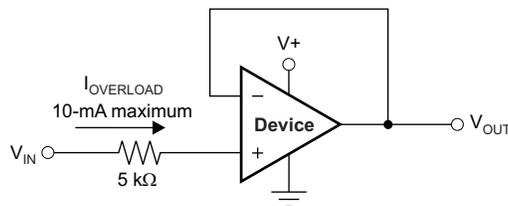
### CAUTION

Supply voltages larger than 6 V may permanently damage the device; see the table.

Place 0.1- $\mu\text{F}$  bypass capacitors close to the power-supply pins to reduce coupling errors from noisy or high-impedance power supplies. For more detailed information on bypass capacitor placement, see the [Layout Guidelines](#) section.

### 9.1 Input and ESD Protection

The LMV3xxA series incorporates internal ESD protection circuits on all pins. For input and output pins, this protection primarily consists of current-steering diodes connected between the input and power-supply pins. These ESD protection diodes provide in-circuit, input overdrive protection, as long as the current is limited to 10-mA, as stated in the table. [Figure 37](#) shows how a series input resistor can be added to the driven input to limit the input current. The added resistor contributes thermal noise at the amplifier input and the value must be kept to a minimum in noise-sensitive applications.



**Figure 37. Input Current Protection**

## 10 Layout

### 10.1 Layout Guidelines

For best operational performance of the device, use good printed circuit board (PCB) layout practices, including:

- Noise can propagate into analog circuitry through the power pins of the circuit as a whole and of op amp itself. Bypass capacitors are used to reduce the coupled noise by providing low-impedance power sources local to the analog circuitry.
  - Connect low-ESR, 0.1- $\mu$ F ceramic bypass capacitors between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is applicable for single-supply applications.
- Separate grounding for analog and digital portions of circuitry is one of the simplest and most-effective methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground planes. A ground plane helps distribute heat and reduces electromagnetic interference (EMI) noise pickup. Ensure to physically separate digital and analog grounds, paying attention to the flow of the ground current. For more detailed information, see [Circuit Board Layout Techniques](#).
- In order to reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If these traces cannot be kept separate, crossing the sensitive trace perpendicular is much better as opposed to in parallel with the noisy trace.
- Place the external components as close to the device as possible, as shown in [Figure 39](#). Keeping R<sub>F</sub> and R<sub>G</sub> close to the inverting input minimizes parasitic capacitance.
- Keep the length of input traces as short as possible. Remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring may significantly reduce leakage currents from nearby traces that are at different potentials.
- Cleaning the PCB following board assembly is recommended for best performance.
- Any precision integrated circuit can experience performance shifts resulting from moisture ingress into the plastic package. Following any aqueous PCB cleaning process, baking the PCB assembly is recommended to remove moisture introduced into the device packaging during the cleaning process. A low-temperature, post-cleaning bake at 85°C for 30 minutes is sufficient for most circumstances.

### 10.2 Layout Example

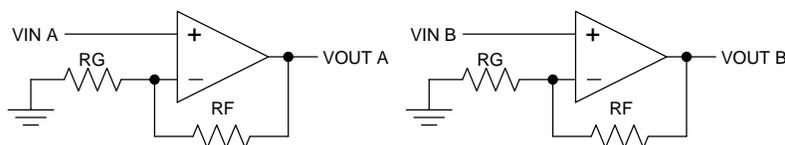


Figure 38. Schematic Representation for [Figure 39](#)

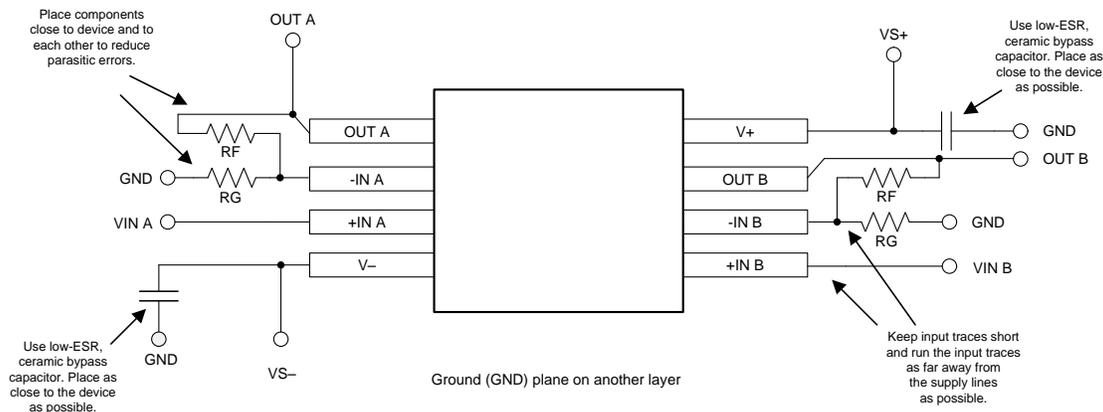


Figure 39. Layout Example

## 11 Device and Documentation Support

### 11.1 Documentation Support

#### 11.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, [EMI Rejection Ratio of Operational Amplifiers application report](#)

#### 11.2 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to order now.

**Table 1. Related Links**

PARTS	PRODUCT FOLDER	ORDER NOW	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
LMV358A	<a href="#">Click here</a>				

#### 11.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

#### 11.4 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

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**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

#### 11.5 Trademarks

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#### 11.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 11.7 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LMV358AIDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	MV358A	<b>Samples</b>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

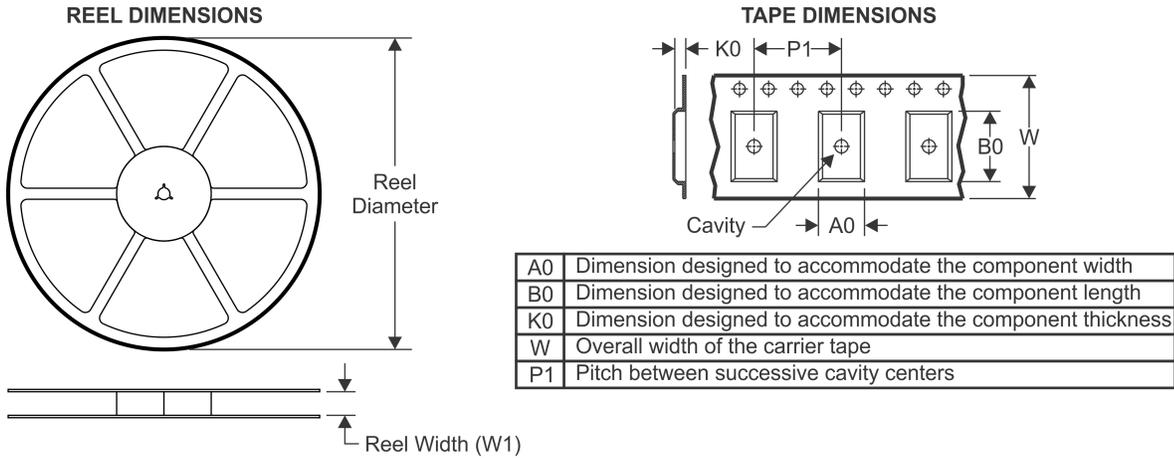
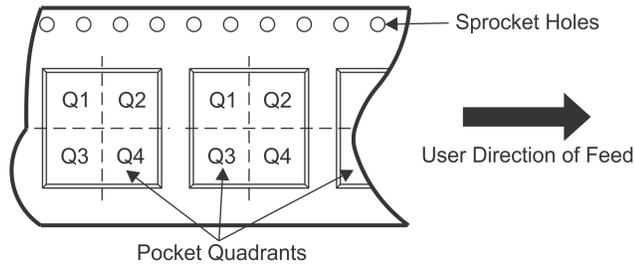
(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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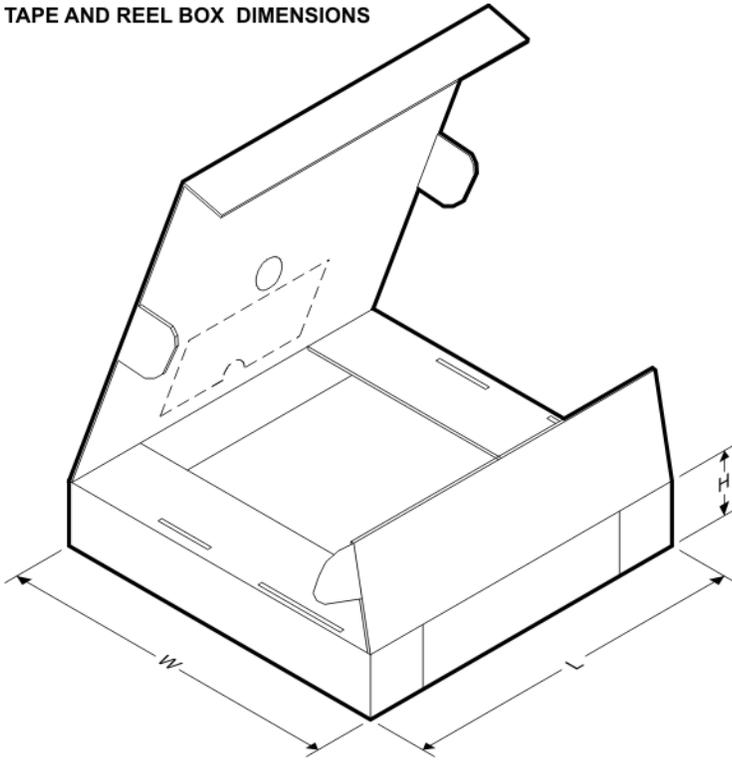
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**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMV358AIDR	SOIC	D	8	2500	330.0	15.4	6.4	5.2	2.1	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS

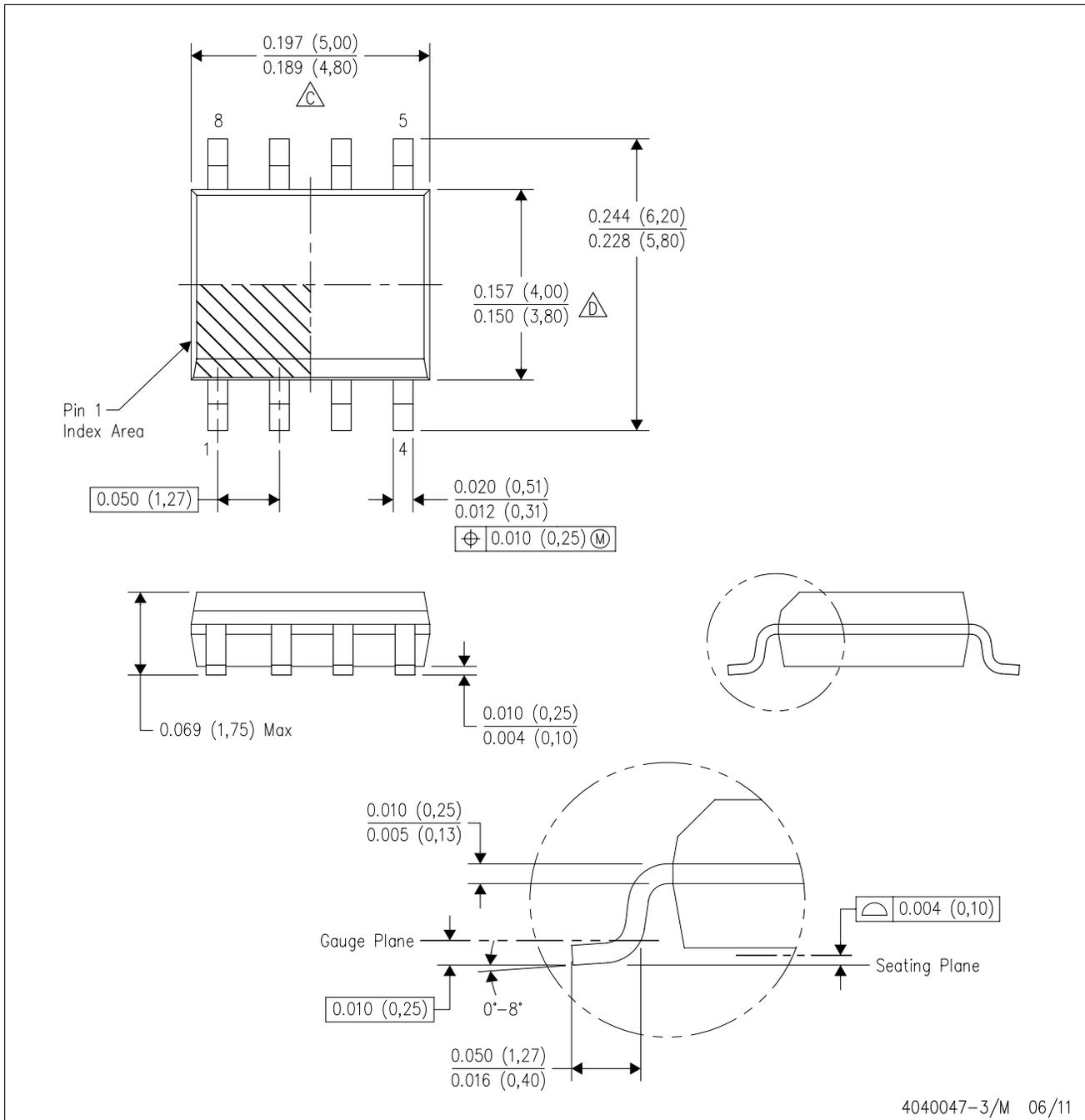


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMV358AIDR	SOIC	D	8	2500	336.6	336.6	41.3

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



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